



RS3AB THRU RS3MB

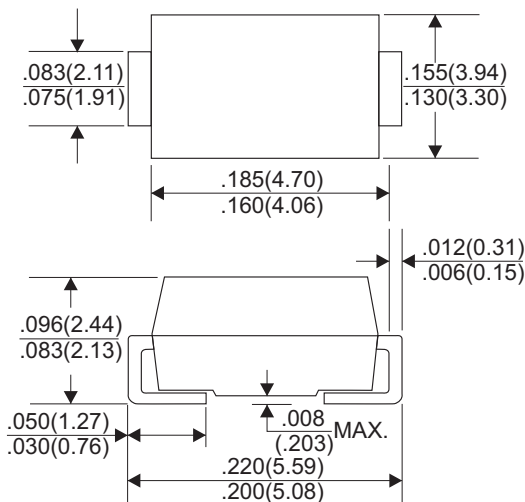
SURFACE MOUNT FAST RECOVERY RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Ampere

DO-214AA(SMB)

FEATURES

- * Glass passivate device
- * Ideal for surface mounted applications
- * Low reverse leakage
- * Metallurgically bonded construction
- * High temperature soldering guaranteed:
250°C/10 seconds 0.375"(9.5mm)lead length,
5 lbs.(2.3kg) tension



Dimensions in inches and (millimeters)

MECHANICAL DATA

- * Case: JEDEC SMB molded plastic
- * Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- * Polarity: Color band denotes cathode end
- * Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	RS3AB	RS3BB	RS3DB	RS3GB	RS3JB	RS3KB	RS3MB	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=55°C	3.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	70							A
Maximum Instantaneous Forward Voltage at 3.0A	1.3							V
Maximum DC Reverse Current Ta=25°C	5.0							µA
at Rated DC Blocking Voltage Ta=100°C	100							µA
Maximum Reverse Recovery Time (Note 1)	150			250		500		nS
Typical Junction Capacitance (Note 2)	40							pF
Operating and Storage Temperature Range Tj, Tstg	-65 — +150							°C
Marking code	RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (RS3AB THRU RS3MB)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

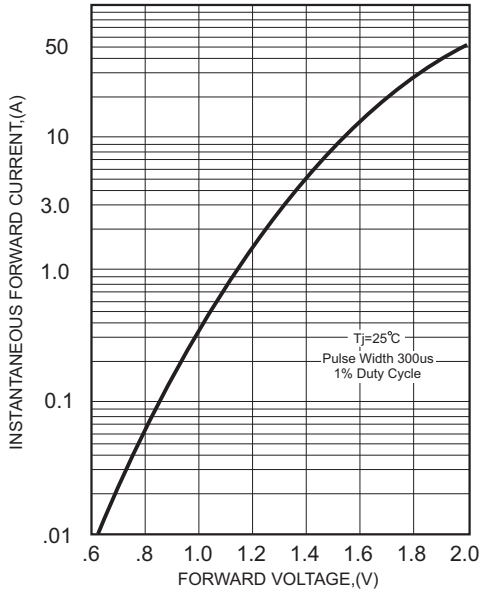


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

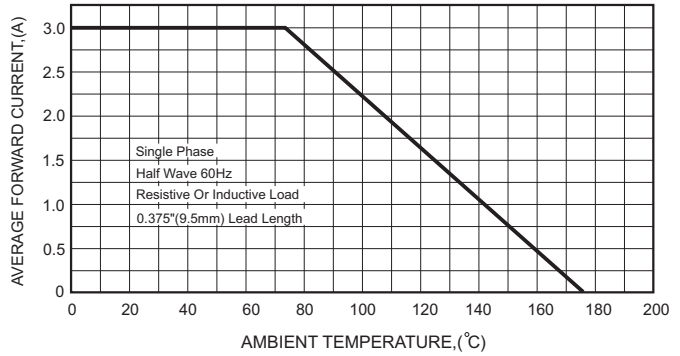


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

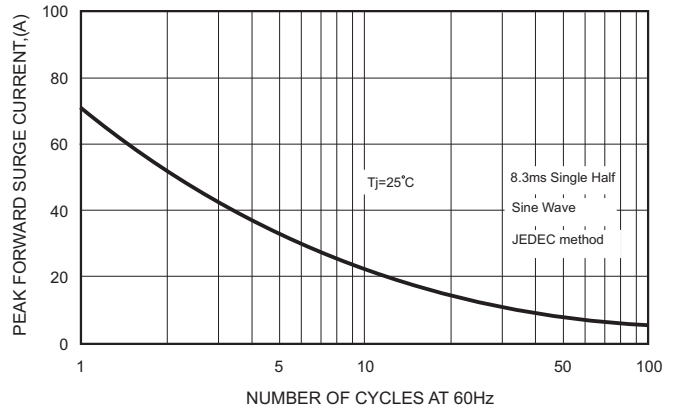
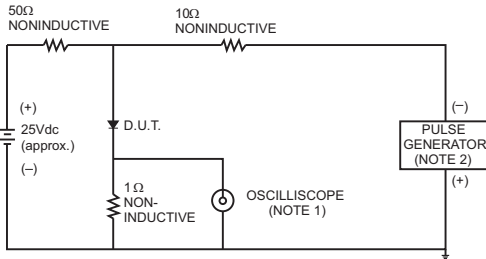


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



- NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

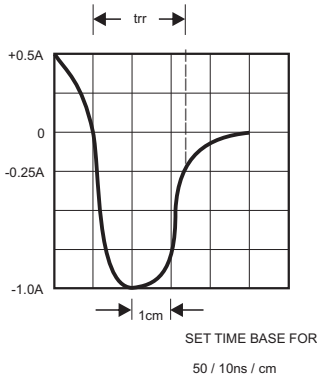


FIG.5-TYPICAL JUNCTION CAPACITANCE

